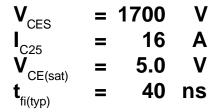


# Advance Technical Data

# **High Voltage IGBT**

# **IXGH 16N170A IXGT 16N170A**



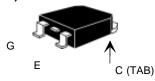


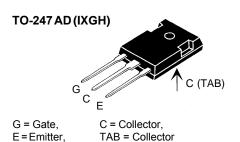
Symbol	<b>Test Conditions</b>		Maximum Ratings	
V <sub>CES</sub>	T <sub>J</sub> = 25°C to 150°C		1700	V
<b>V</b> <sub>CGR</sub>	$T_{_{\rm J}}$ = 25°C to 150°C; $R_{_{\rm GE}}$ = 1 M $\Omega$		1700	V
V <sub>GES</sub>	Continuous		±20	V
V <sub>GEM</sub>	Transient		±30	V
I <sub>C25</sub>	T <sub>C</sub> = 25°C		16	A
I <sub>C90</sub>	T <sub>C</sub> = 90°C		8	Α
I <sub>CM</sub>	$T_{c} = 25^{\circ}C$ , 1 ms		40	Α
SSOA (RBSOA)	$V_{GE}$ = 15 V, $T_{VJ}$ = 125°C, $R_{G}$ = 10 $\Omega$ Clamped inductive load		I <sub>CM</sub> = 40 @ 0.8 V <sub>CES</sub>	A
t <sub>sc</sub>	$T_J = 125^{\circ}C, V_{CE} = 1200 \text{ V}; V_{GE} = 1$	5 V, R <sub>G</sub> = 22	Ω 10	μs
P <sub>c</sub>	T <sub>C</sub> = 25°C		190	W
$\overline{T_{J}}$			-55 +150	°C
T <sub>JM</sub>			150	°C
$T_{stg}$			-55 +150	°C
M <sub>d</sub>	Mounting torque (M3)	(TO-247)	1.13/10Nn	n/lb.in.
	ead temperature for soldering 062 in.) from case for 10 s		300	°C
Weight		TO-247	6	g
		TO-268	4	g

l <sub>C25</sub>	$T_{c} = 25^{\circ}C$		16	Α
I <sub>C90</sub>	$T_{c} = 90^{\circ}C$		8	Α
I <sub>CM</sub>	$T_{\rm C}$ = 25°C, 1 ms		40	Α
SSOA (RBSOA)	$V_{GE}$ = 15 V, $T_{VJ}$ = 125°C, $R_{G}$ = 10 Clamped inductive load	Ω	I <sub>CM</sub> = 40 @ 0.8 V <sub>CES</sub>	A
t <sub>sc</sub>	$T_J = 125$ °C, $V_{CE} = 1200$ V; $V_{GE} = 1200$ V; $V_{GE} = 1200$ V; $V_{CE} = 1200$	= 15 V, $R_{\rm G} = 22\Omega$	10	μs
P <sub>c</sub>	T <sub>C</sub> = 25°C		190	W
$T_{J}$			-55 +150	°C
$T_{JM}$			150	°C
$T_{stg}$			-55 +150	°C
M <sub>d</sub>	Mounting torque (M3)	(TO-247)	1.13/10Nn	n/lb.in.
	ead temperature for soldering 062 in.) from case for 10 s		300	°C
Weight		TO-247	6	g
		TO-268	4	g
Cymphal	Toot Conditions	Ch	arastariatia \/	مميياه

Symbol	Test Conditions Cha $(T_J = 25^{\circ}C, \text{ unless o min.})$		ristic Val se specif   max.	
BV <sub>CES</sub>	$I_{C} = 250 \mu\text{A},  V_{GE} = 0 \text{V}$ 1700 $I_{C} = 250 \mu\text{A},  V_{CE} = V_{GE}$ 3.0		5.0	V V
I <sub>CES</sub>	$V_{CE} = 0.8 \cdot V_{CES}$ $T_{J} = 25^{\circ}C$ $V_{GE} = 0 V$ Note 1 $T_{J} = 125^{\circ}C$		50 750	μ <b>Α</b> μ <b>Α</b>
GES	$V_{CE} = 0 \text{ V}, V_{GE} = \pm 20 \text{ V}$		±100	nΑ
V <sub>CE(sat)</sub>	$I_{c} = I_{c90}, V_{GE} = 15 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$ $T_{J} = 125^{\circ}\text{C}$	4.0 4.8	5.0	V V

### TO-268 (IXGT)





## **Features**

- International standard packages JEDEC TO-268 and JEDEC TO-247 AD
- High current handling capability
- MOS Gate turn-on
- drive simplicity
- Rugged NPT structure
- Molding epoxies meet UL 94 V-0 flammability classification

### **Applications**

- Capacitor discharge & pulser circuits
- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies

### **Advantages**

- · High power density
- Suitable for surface mounting
- Easy to mount with 1 screw, (isolated mounting screw hole)



Symbol		Characteristic Values (T <sub>1</sub> = 25°C, unless otherwise specified)		
	(1 <sub>J</sub> = 25°C, unless to min.	typ.	max.	
g <sub>fs</sub>	$I_{C} = I_{C25}$ ; $V_{CE} = 10 \text{ V}$ Note 2	10	S	
$\mathbf{C}_{ies}$		1700	pF	
$\mathbf{C}_{oes}$	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	83	pF	
$\mathbf{C}_{res}$	J	30	pF	
$\mathbf{Q}_{g}$		65	nC	
$\mathbf{Q}_{\mathrm{ge}}$	$I_{\rm C} = I_{\rm C90}, V_{\rm GE} = 15  \text{V}, V_{\rm CE} = 0.5  \text{V}_{\rm CES}$	13	nC	
$\mathbf{Q}_{gc}$	)	24	nC	
$\mathbf{t}_{d(on)}$	Inductive load, T <sub>J</sub> = 25°C	36	ns	
t <sub>ri</sub>	$I_{\rm C} = I_{\rm C25}, V_{\rm GE} = 15  \rm V$	57	ns	
$\mathbf{t}_{\text{d(off)}}$	$R_{\rm G} = 10 \Omega, V_{\rm CE} = 0.8 V_{\rm CES}$	200	350 ns	
t <sub>fi</sub>	Note 3	40	150 ns	
E <sub>off</sub>		0.9	1.5 mJ	
t <sub>d(on)</sub>	Inductive load, T <sub>J</sub> = 125°C	38	ns	
t <sub>ri</sub>	$I_{\rm C} = I_{\rm C25}, V_{\rm GE} = 15 \rm V$	59	ns	
E <sub>on</sub>	$R_{\rm G}$ = 10 $\Omega$ , $V_{\rm CE}$ = 0.8 $V_{\rm CES}$	1.5	mJ	
t <sub>d(off)</sub>	/ Note 3	200	ns	
t <sub>fi</sub>		55	ns	
E <sub>off</sub>		1.1	mJ	
R <sub>thJC</sub>			0.65 K/W	
R <sub>thCK</sub>	(TO-247)	0.25	K/W	

- Notes: 1. Device must be heatsunk for high temperature leakage current measurements to avoid thermal runaway.
  - 2. Pulse test,  $t \le 300 \mu s$ , duty cycle  $\le 2 \%$
  - 3. Switching times may increase for  $V_{CE}$  (Clamp) > 0.8  $V_{CES}$ , higher  $T_J$  or increased R<sub>G</sub>.

#### **TO-247 AD Outline** Dim. Millimeter Inches Max. Max. Min. Min. .209 4.7 5.3 .185 2.54 .087 .102 2.2 2.6 .059 .098 1.0 1.4 .040 .055 1.65 2.13 .065 .084 3.12 .123 С .016 .031 D 20.80 21.46 .819 .845 Е 15.75 16.26 .610 .640 0.205 0.225 e L 5.20 5.72

19.81

3.55

5.89

4.32

6.15 BSC

L1

ØP

Q

R

20.32

4.50

3.65

6.40

5.49

.780

.140

.170

0.232 0.252

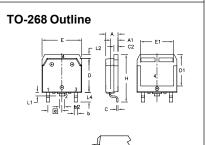
242 BSC

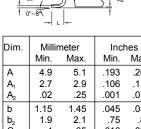
.800

.177

.144

.216





Α	4.9	5.1	.193	.201	
A₁	2.7	2.9	.106	.114	
A <sub>2</sub>	.02	.25	.001	.010	
b	1.15	1.45	.045	.057	
b <sub>2</sub>	1.9	2.1	.75	.83	
С	.4	.65	.016	.026	
D	13.80	14.00	.543	.551	
E	15.85	16.05	.624	.632	
E₁	13.3	13.6	.524	.535	
е	5.45	BSC	.215 BSC		
Н	18.70	19.10	.736	.752	
L	2.40	2.70	.094	.106	
L1	1.20	1.40	.047	.055	
L2	1.00	1.15	.039	.045	
L3	0.2	5 BSC	.010 BSC		
L4	3.80	4.10	.150	.161	

5,486,715